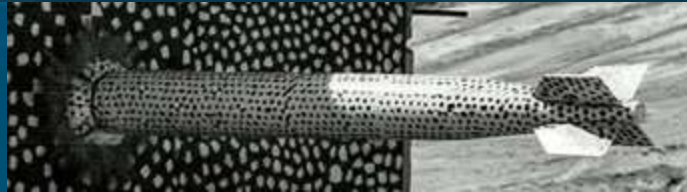
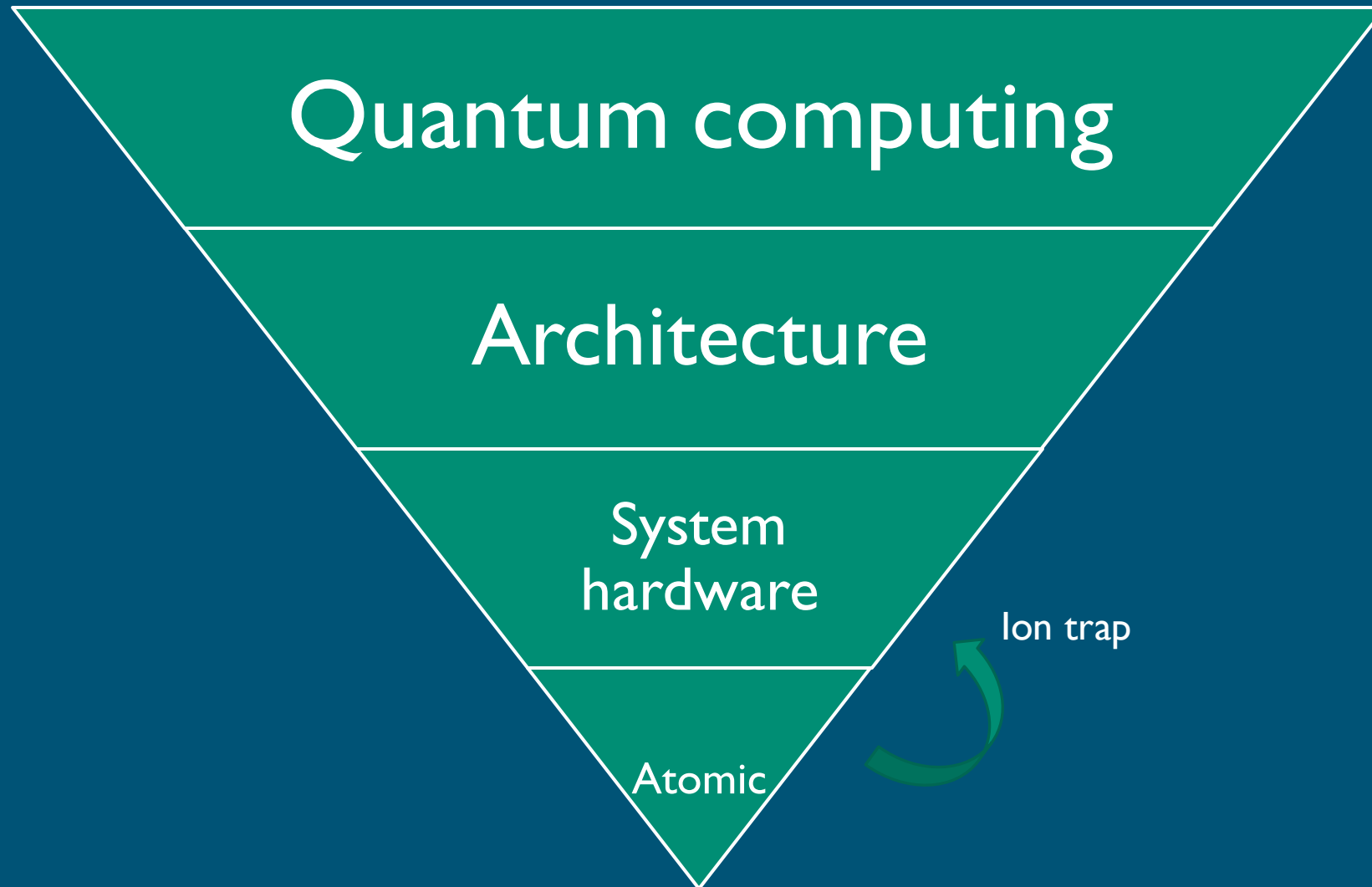


Surface ion traps for quantum computing



May 17, 2021

Daniel Stick, Sandia National Laboratories



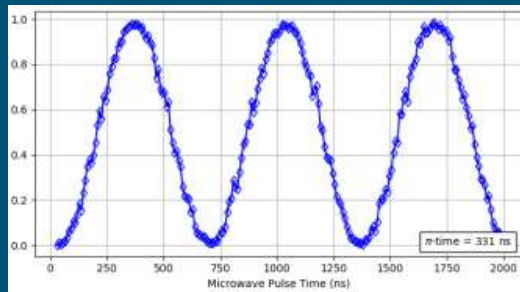
Classical computers

- Discrete states:
 - $|0\rangle$ or $|1\rangle$ (or $|10\rangle$ or $|11\rangle$...)
- Only “local” operations

versus...

Quantum computers

- Superposition states:
 - $\alpha|0\rangle + \beta|1\rangle$ (or $\gamma|10\rangle + \delta|11\rangle + \dots$)



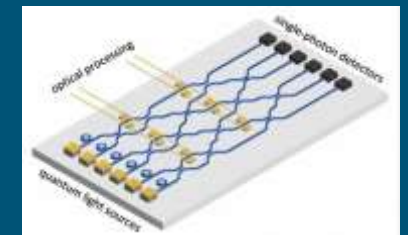
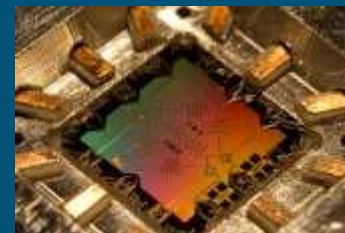
- Entanglement (non-classical states)
 - $\alpha|00\rangle + \beta|11\rangle$

Exponential speedup for particular algorithms

- Quantum simulations
- Optimization/machine learning
- Factoring (Shor’s algorithm)
- And there are caveats and limits within these categories!

There are multiple viable technologies

- Ion traps
- Superconducting JJ
- Neutral atoms
- Solid state: quantum dots/donors
- Photons



QCCD architecture

“Architecture for a large-scale ion-trap quantum computer,”
D. Kielpinski, C. Monroe, and D. J. Wineland, Nature 417, 709 (2002).

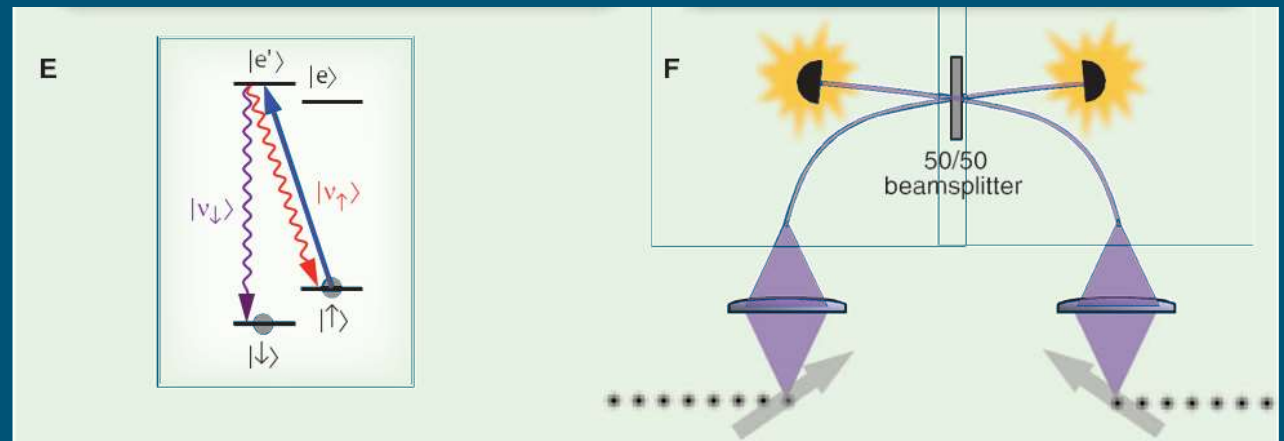
- Originally proposed in 2002
- Achieves ND connectivity using ion transport (at cost of transport time)
- Strengths: all primitives demonstrated
- Weaknesses: transport speed, motional heating during transport



MUSIQC architecture

“Large Scale Modular Quantum Computer Architecture with Atomic Memory and Photonic Interconnects,” C. Monroe, R. Raussendorf, A. Ruthven, K. R. Brown, P. Maunz, L.-M. Duan, J. Kim, Phys. Rev. A 89, 022317 (2014).

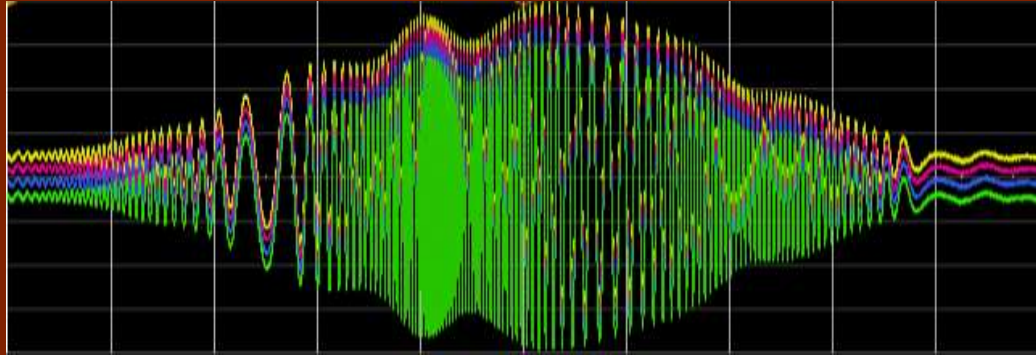
- Originally proposed in 2014
- Achieves ND connectivity using a combination of ion transport, radial mode operations, and photonic interconnects
- Strengths: photons are a transportable, potentially universal qubit, all primitives demonstrated, “modular”; faster early scaling
- Weaknesses: lacks scalable demonstration of photonic interconnect



Trapped Ion Quantum Computing: system hardware level



Electrical control system



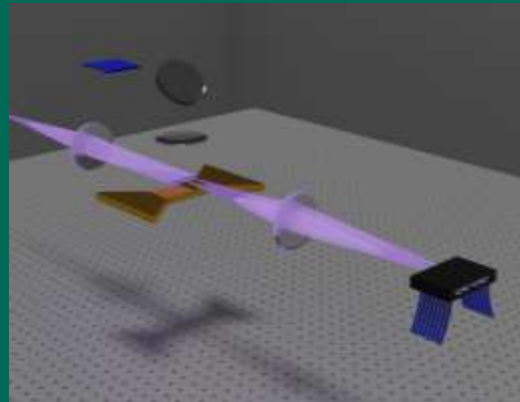
Imaging



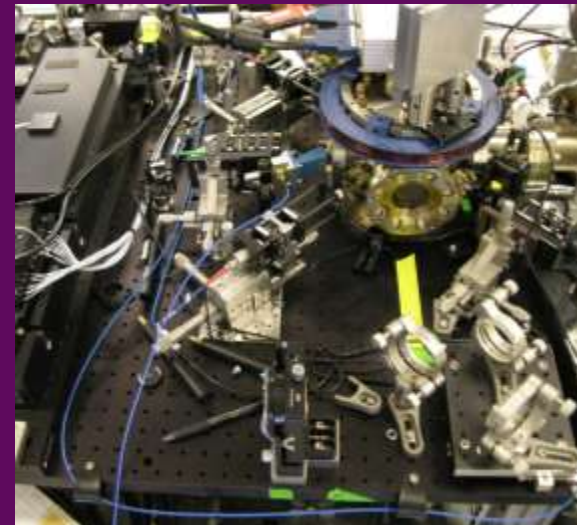
Lasers



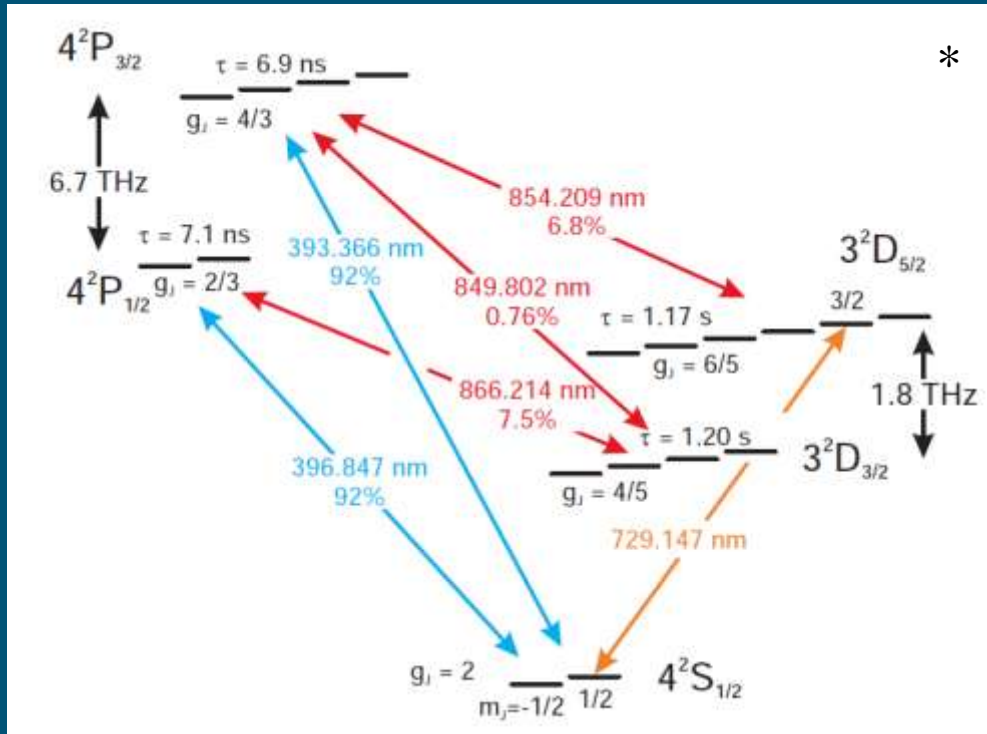
Optical modulators & delivery



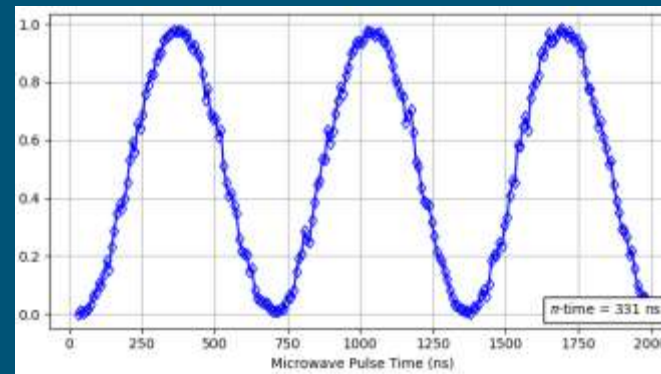
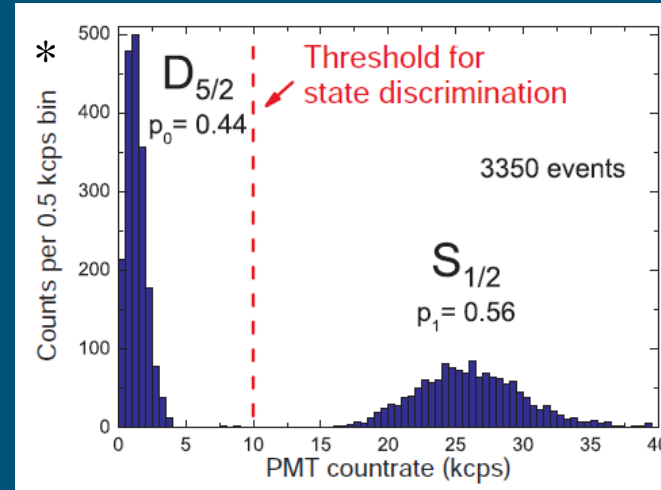
Vacuum/cryo chamber



Trap + package



* “Precision spectroscopy and quantum information processing with trapped calcium ions”, Jan Benhelm PhD Thesis (2008)



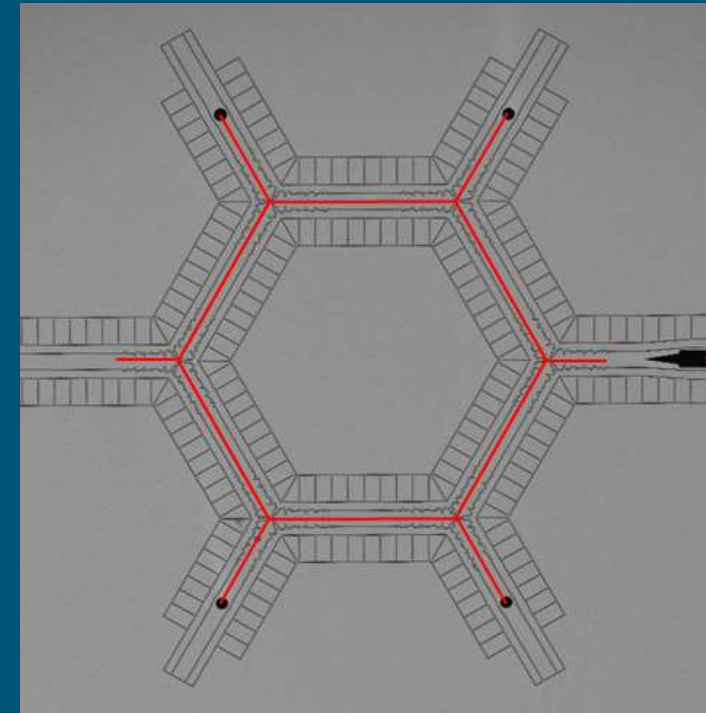
Physical errors (best demonstrations from multiple groups)

- 1Q error: $1e-5$
- 2Q error: $1e-3$
- Detect, prep: $<1e-4$
- T_1 : 1s ... infinite
- T_2 : 10 ms ... 10 s

Trapped Ion Quantum Computing: trap level



- Using electric fields we can trap multiple individual ions, move them around, and probe them with lasers
- Stored in an ultra-high vacuum environment at room or cryogenic temperatures
- Lasers are tuned based on the atomic structure of the ion.
 - Many species are used (Ca, Yb, Be, Mg, Ba, ...)
 - Used to perform quantum operations (microwaves can do the same thing)

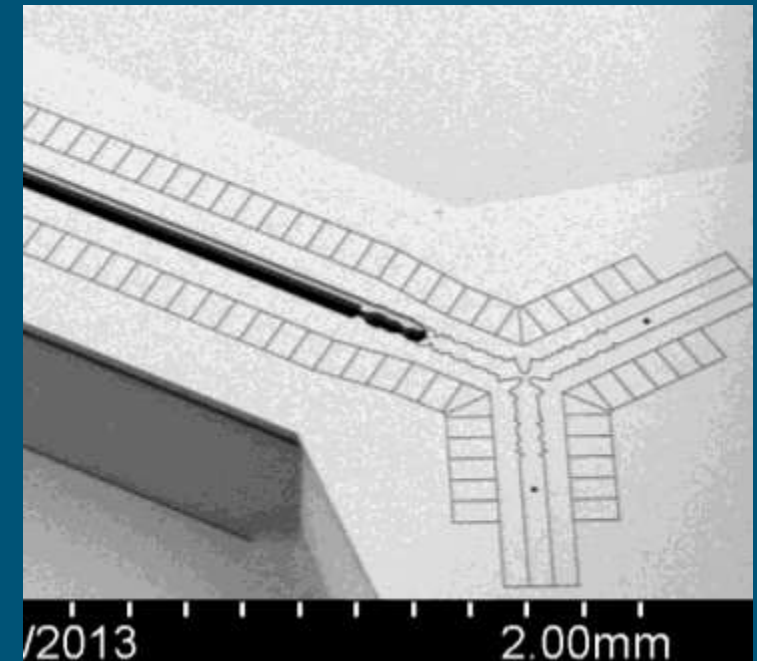
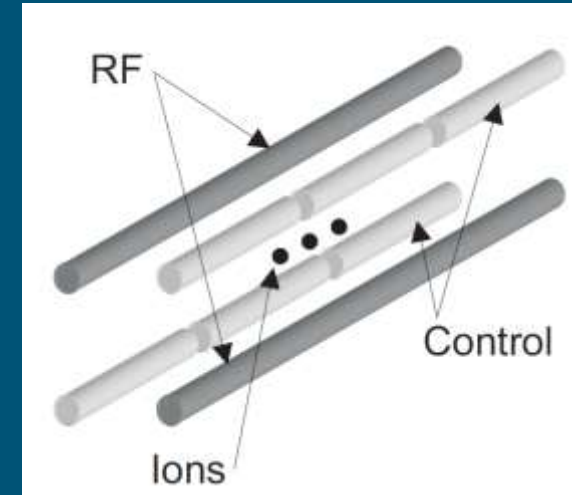


Advantages

- More manufacturable (“scalable”)
- Consistent geometry -> consistent behavior
- Greater field control (more electrodes)
- 2D geometry
- Integration of other technologies (waveguides, detectors, filters...)
- Laser access

Challenges

- Low depth (ion lifetime), anharmonicities in potential
- Proximity to surface (charging, heating)
- Delicate (dust, voltage)
- Capacitance (high power dissipation)



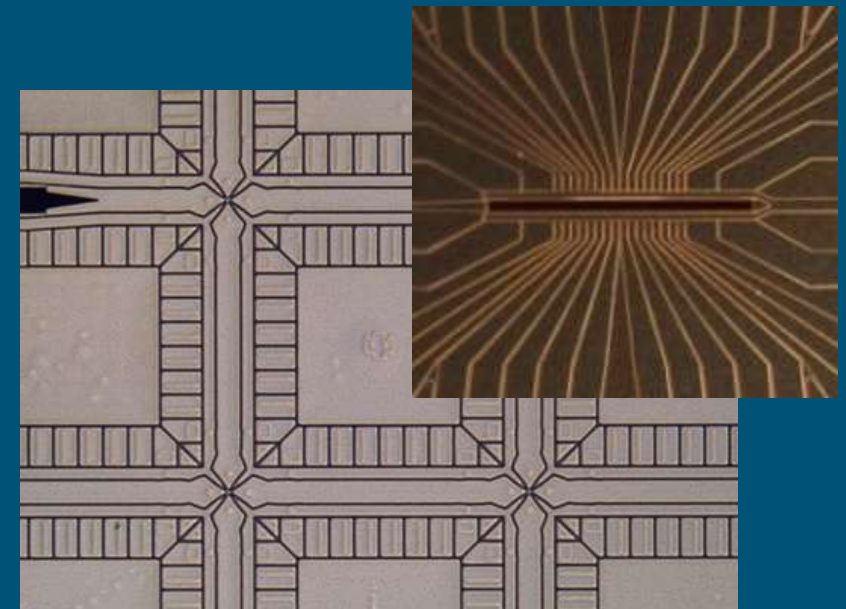
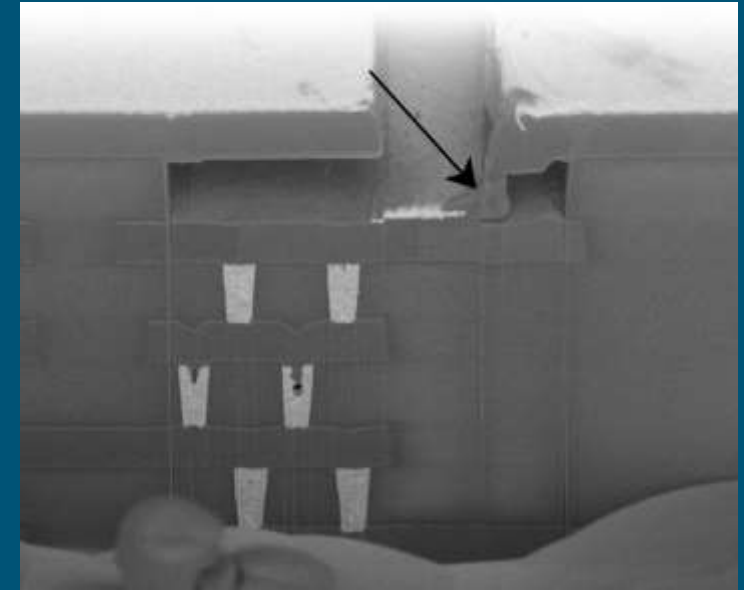
Ion traps: derived requirements

Essential capabilities

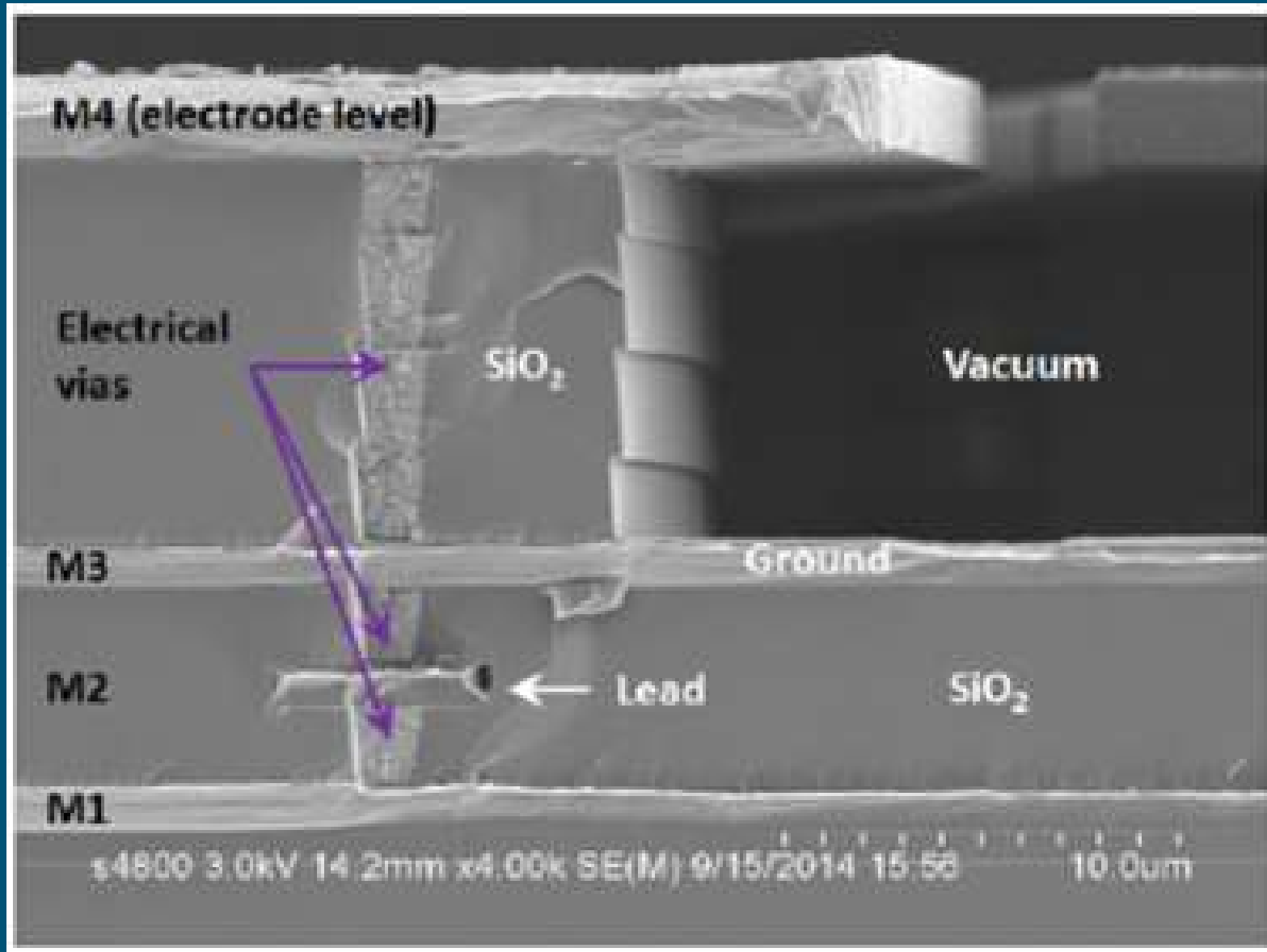
- Store ions for long periods of time (hours)
- Move ions to achieve 2D connectivity
- Support high fidelity operations
- Uniform performance

Derived requirements

- Voltage breakdown $>300\text{V}$ @ $\sim 50\text{ MHz}$
- Backside loading hole
- Multi-level lead routing for accessing interior electrodes
- Standardization [lithographically defined electrodes]
- Overhung electrodes
- High optical access [high NA delivery and collection optics]



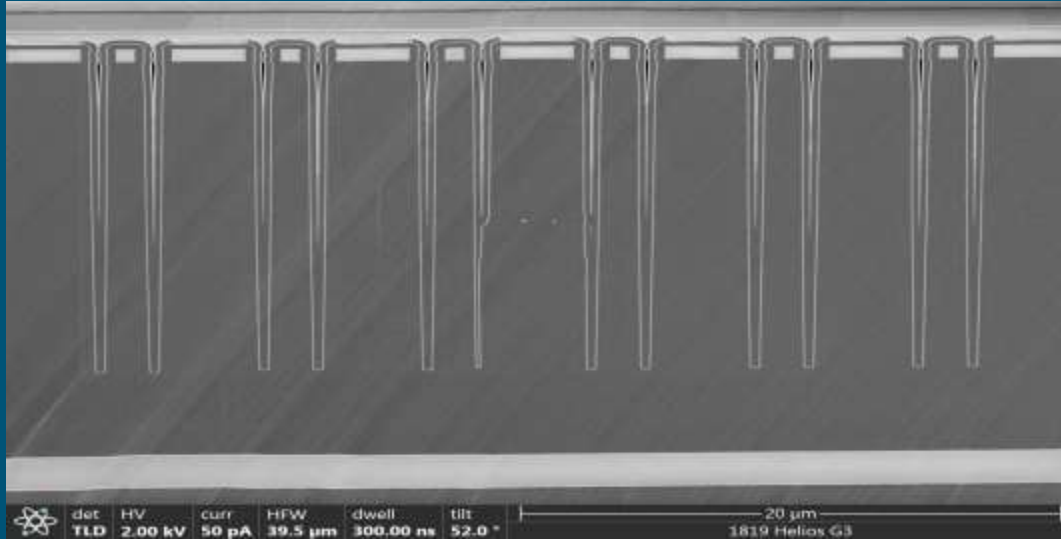
Ion traps: multiple metal levels



II Ion traps: trench capacitors and loading holes



Capacitors



Interposer (current)

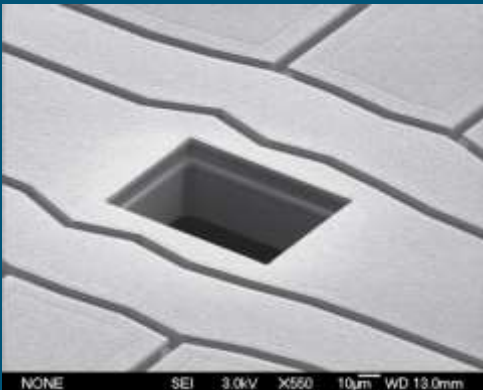
- 20V max voltage
- 1 nF capacitance

On chip

- 15V max voltage
- 200 pF capacitance (but low inductance)
- Up to 200 capacitors can be located within the isthmus

Loading holes

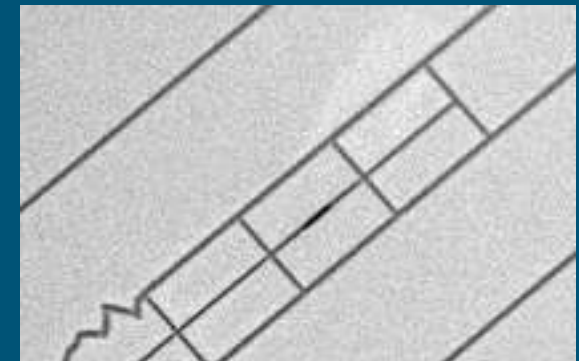
50 μm \times 80 μm
modulation necessary



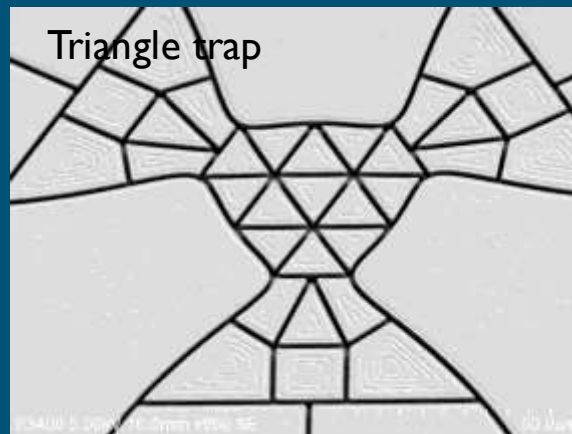
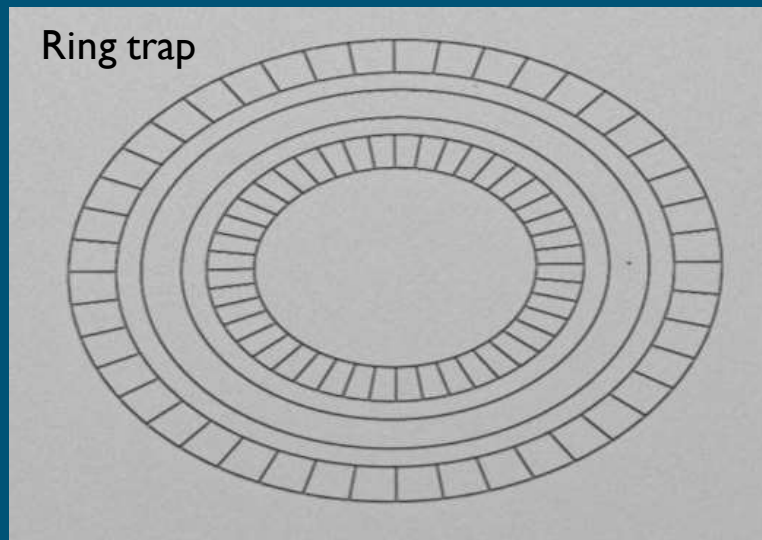
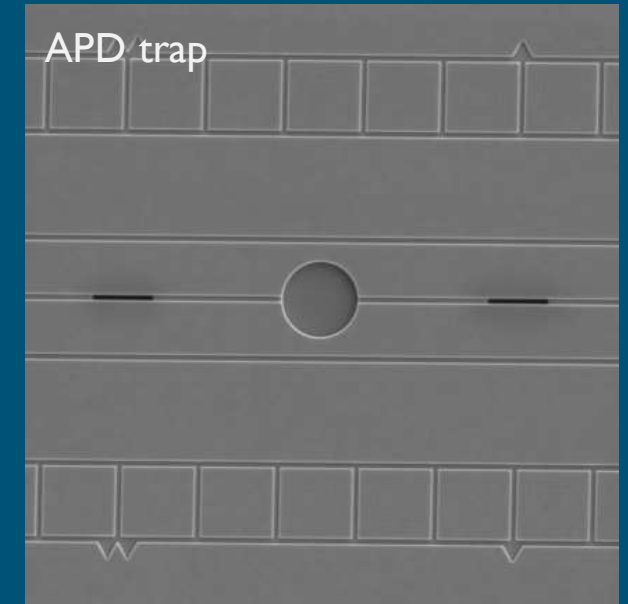
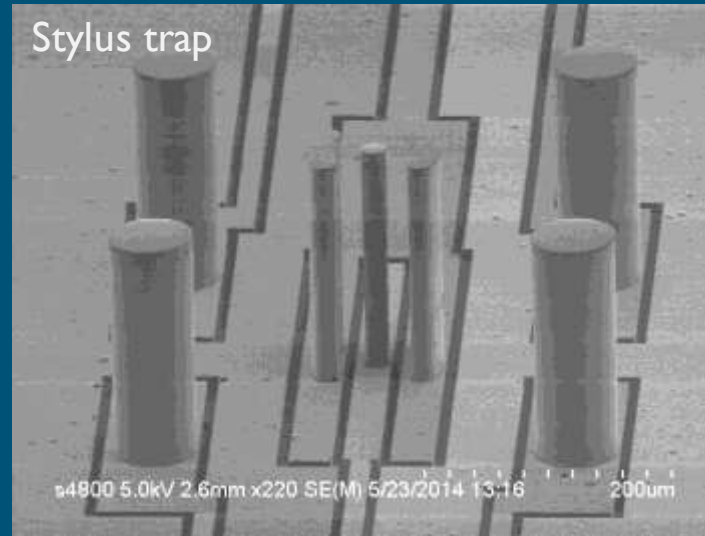
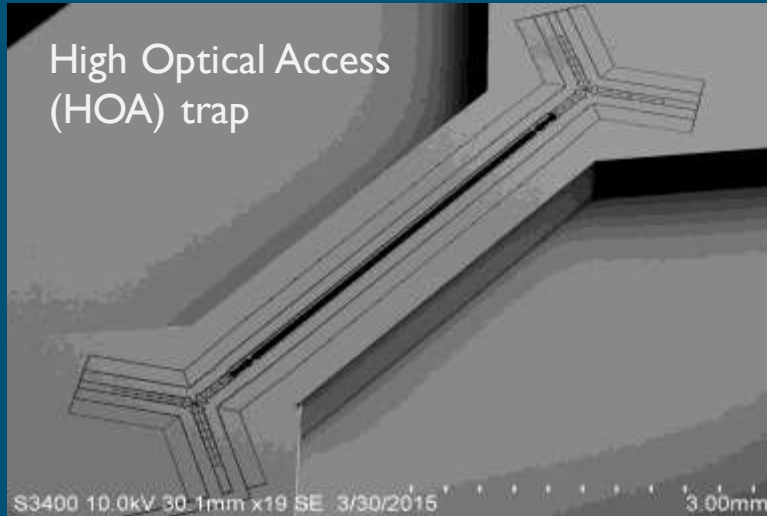
10 μm hole
still perturbs the field



3 μm \times 20 μm



Ion traps: Sandia's trap zoo (partial list)

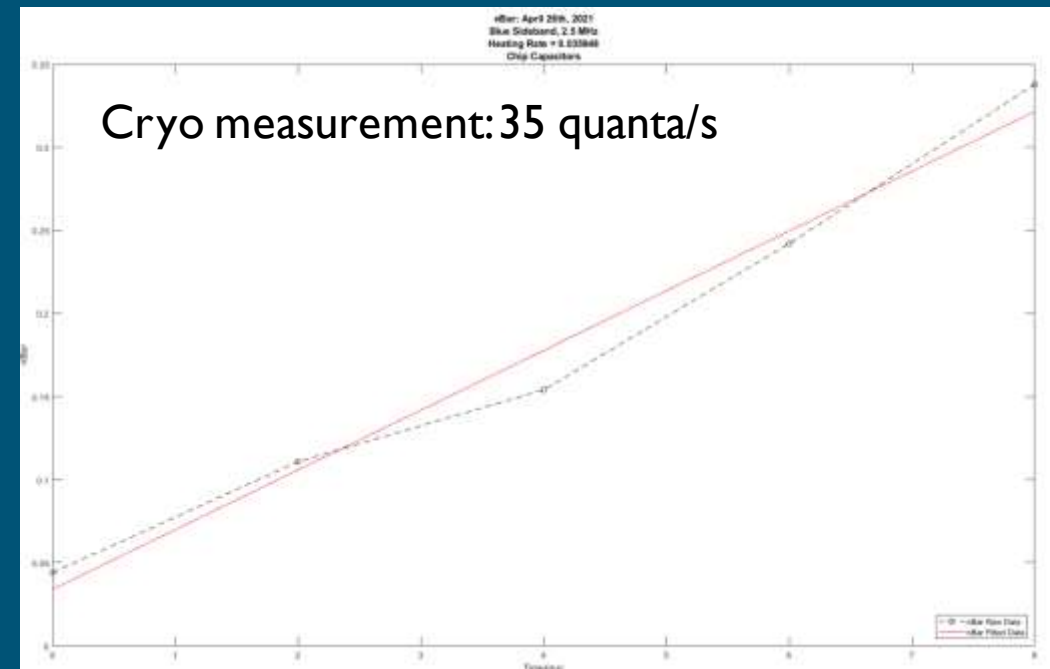
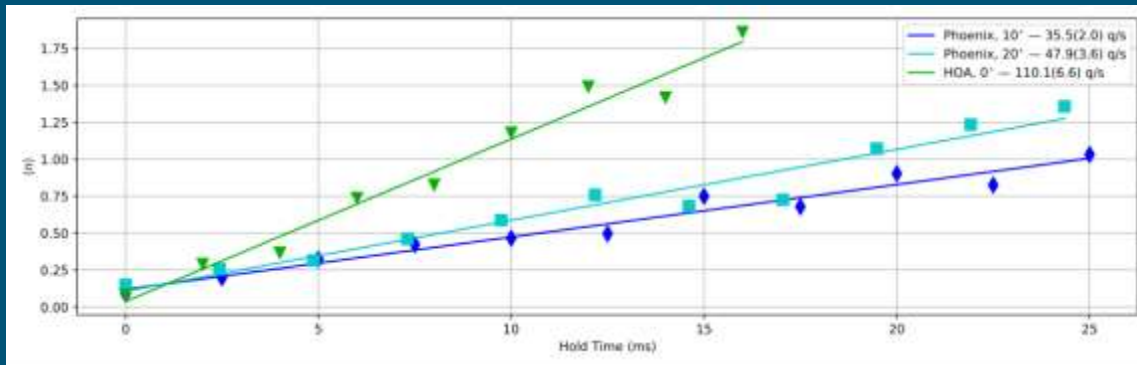


Trap characterization: motional heating



Electric field noise on the trap electrodes heats the ion. This can be due to a variety of sources (Johnson noise of resistors, DAC voltage noise, ...) but these can be reduced to a low level, leaving “anomalous heating sources”.

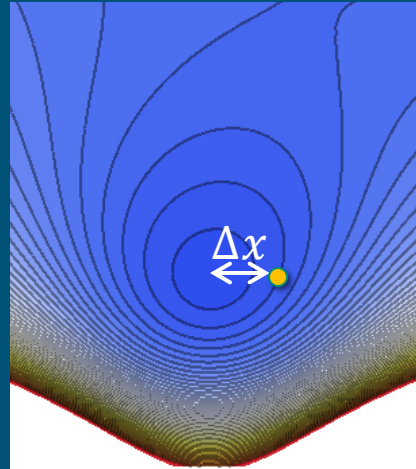
- Many groups have studied dependence on trap temperature, surface treatment, frequency
- Recently several groups have observed that heating at cryogenic temperatures does not drop as expected with multi-metal level silicon traps. We are collecting data on variants (capacitor, substrate resistivity, additional films like polysilicon, nitride, oxide, and ion height)



Trap characterization: background electric field



Positioning an ion at the RF null to eliminate driven micromotion



RF driven motion (from MATTHEW EQN)

a OFFSET

b SECULAR

$$U_i(t) \approx \left[U_{0i} + U_{1i} \cos(\omega_i t + \phi_i) \right] \left[1 + \frac{q_i}{2} \cos(\Omega t) \right]$$

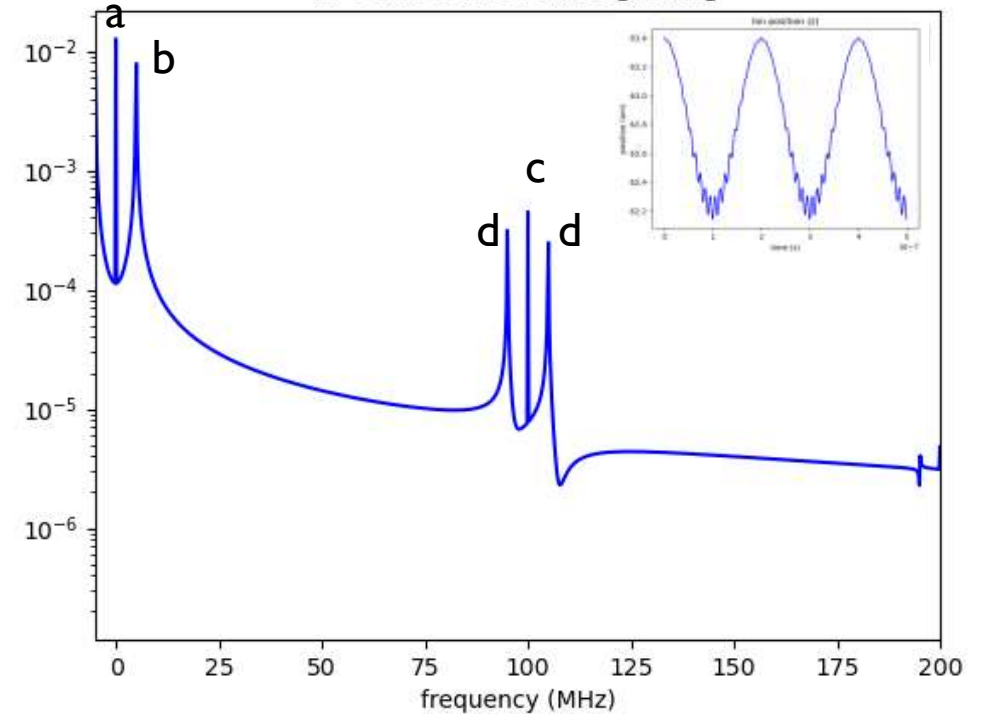
c

DRIVEN
MOTION

d

MOTION (NORMAL?)

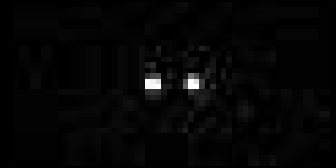
FFT of ion motion, beginning



Trap characterization: **controlled transport**



Controlled rotation



Combined rotation and translation



Separation and merging



Long Chains



Compression of chains

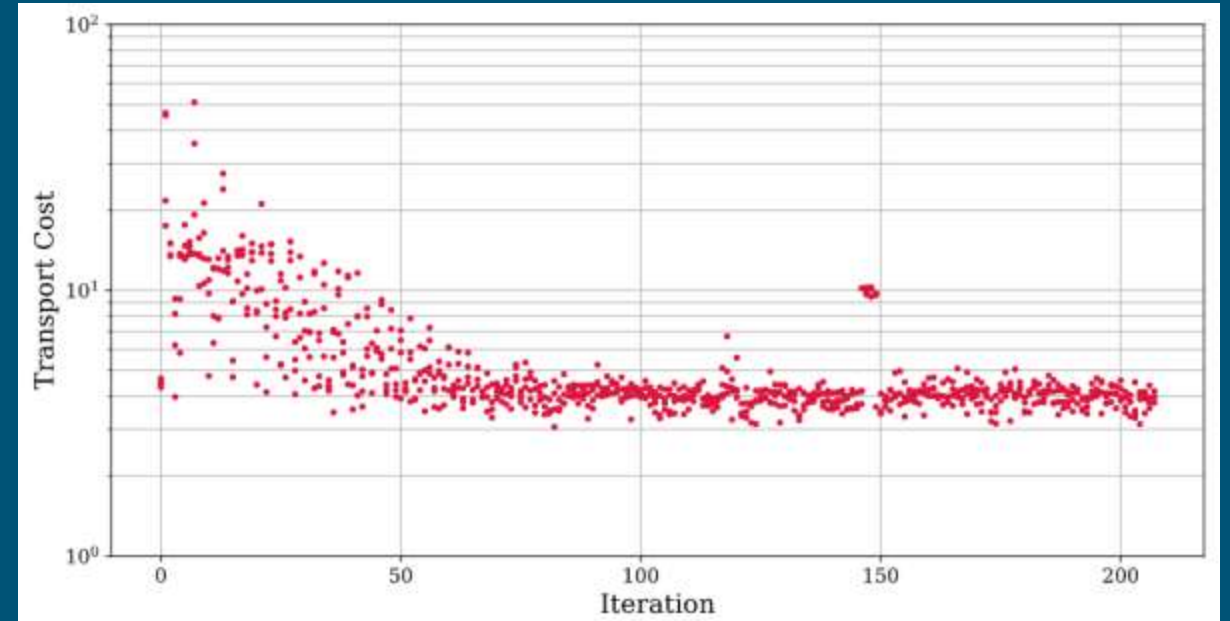


3D Crystal Structures



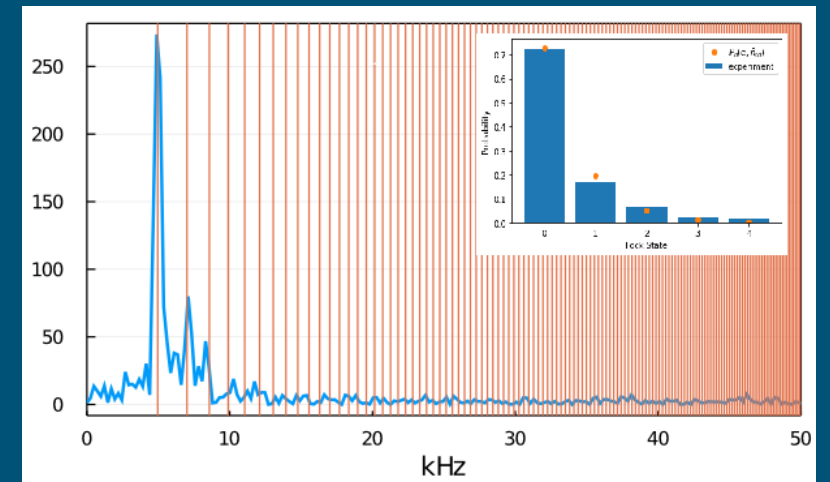
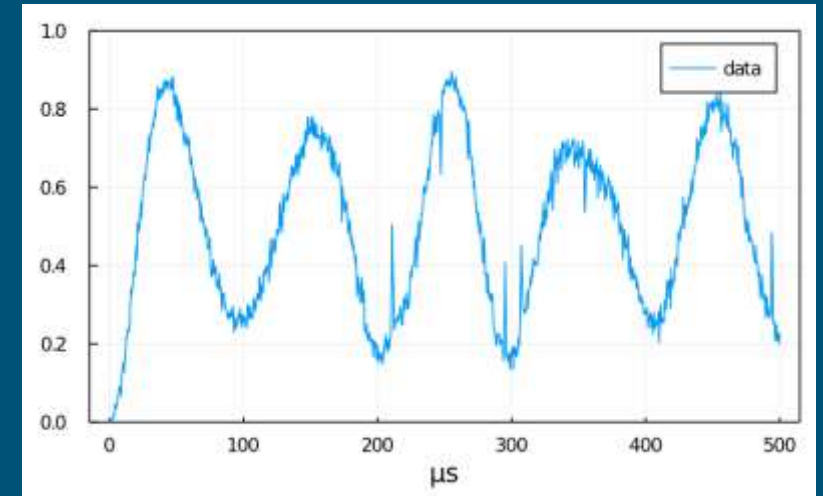
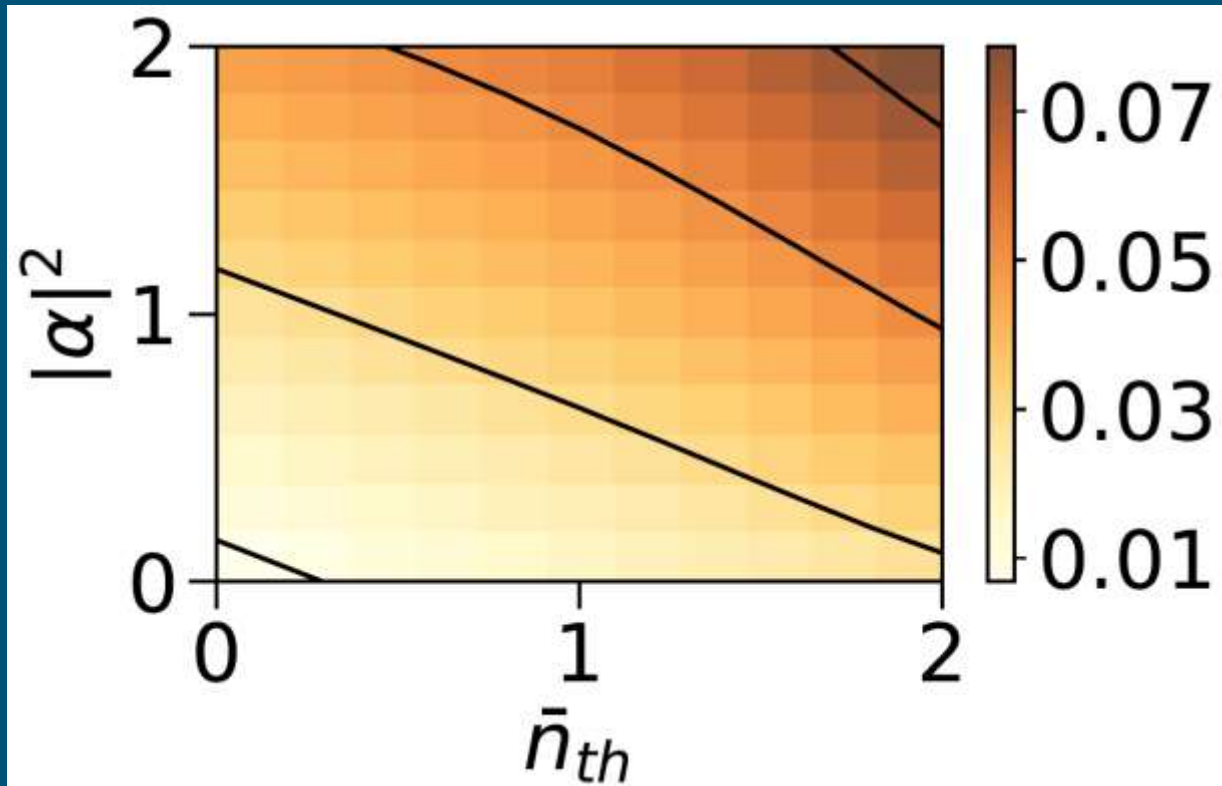
Using Nelder-Mead optimization

- What is this optimizing?
 - Inaccuracies in simulation
 - Background electric field
 - Variation of filter components
- Optimization protocol
 - 3 Bezier coefficients
 - 6 axial frequency points
- Measurement
 - 120 iterations with short probe
 - Followed by 200 iterations at a longer probe time
 - Varied delay time at end point
- Velocity: 0.5 electrodes/ μs . (6 μs to go 210 μm)

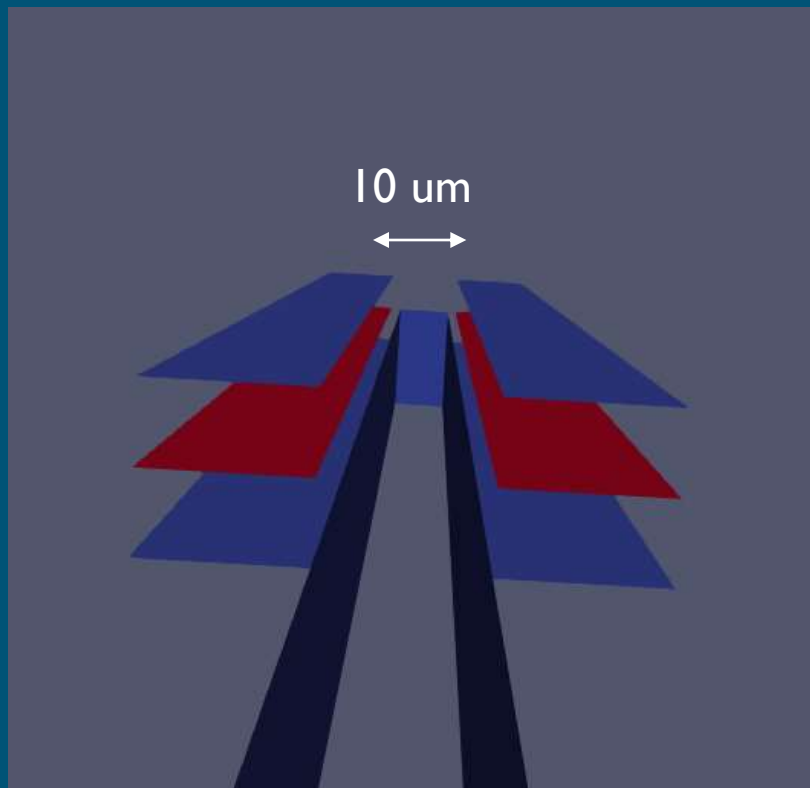


offset	\bar{n}
0 steps	0.38 ± 0.04
3 steps	0.71 ± 0.10
6 steps	0.58 ± 0.07
9 steps	0.26 ± 0.03

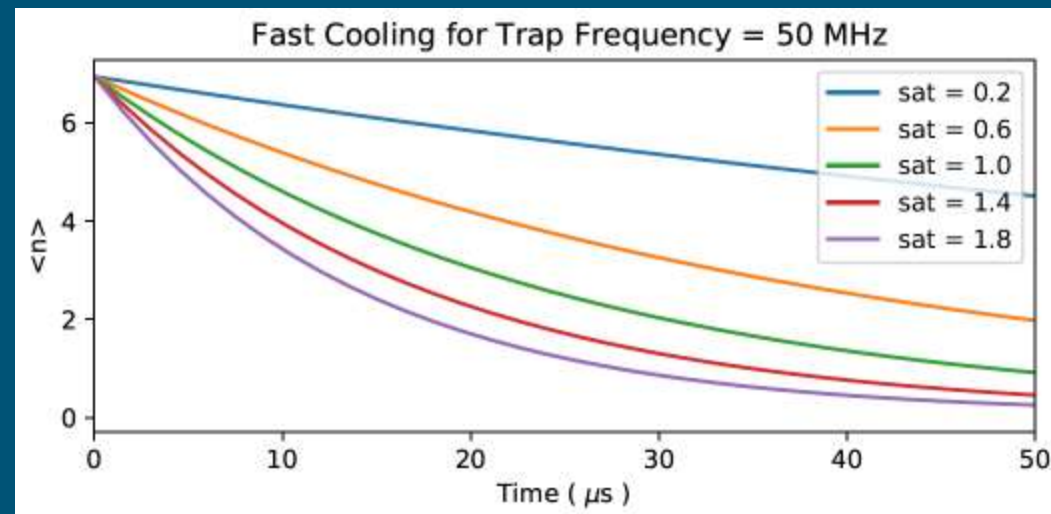
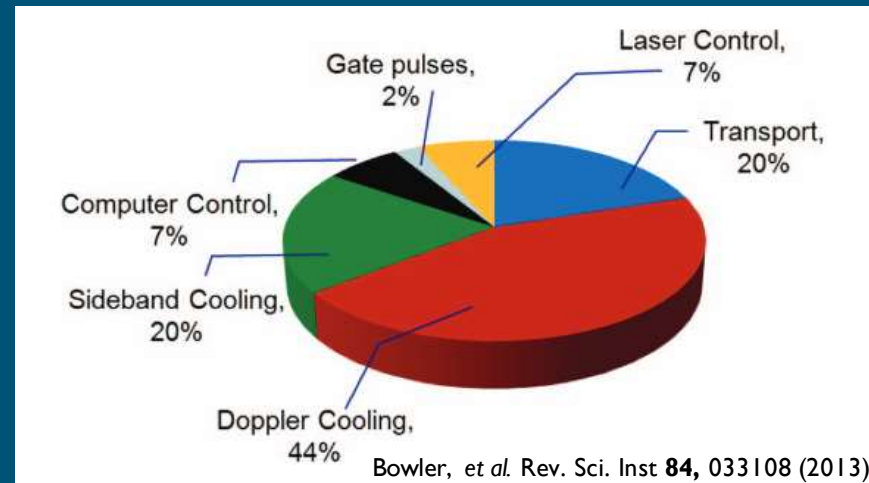
Infidelity vs coherent and thermal motional excitation



Very miniaturized traps: high frequency



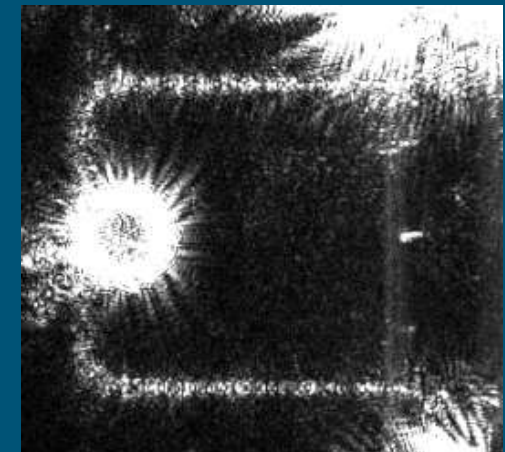
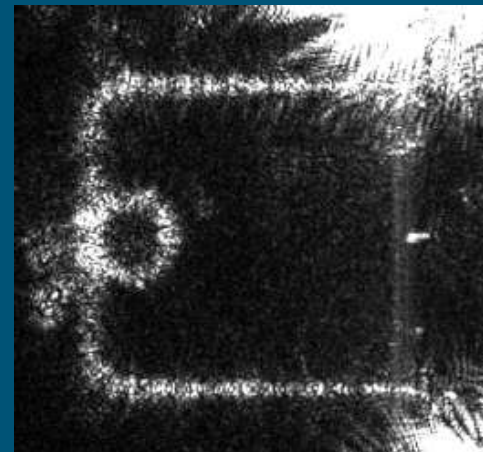
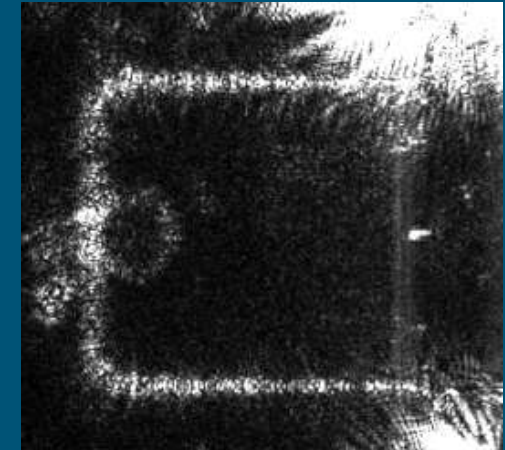
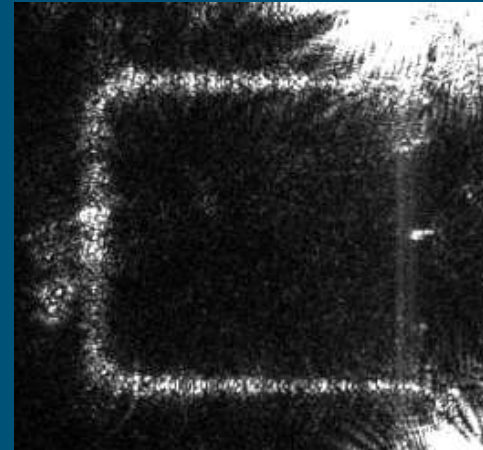
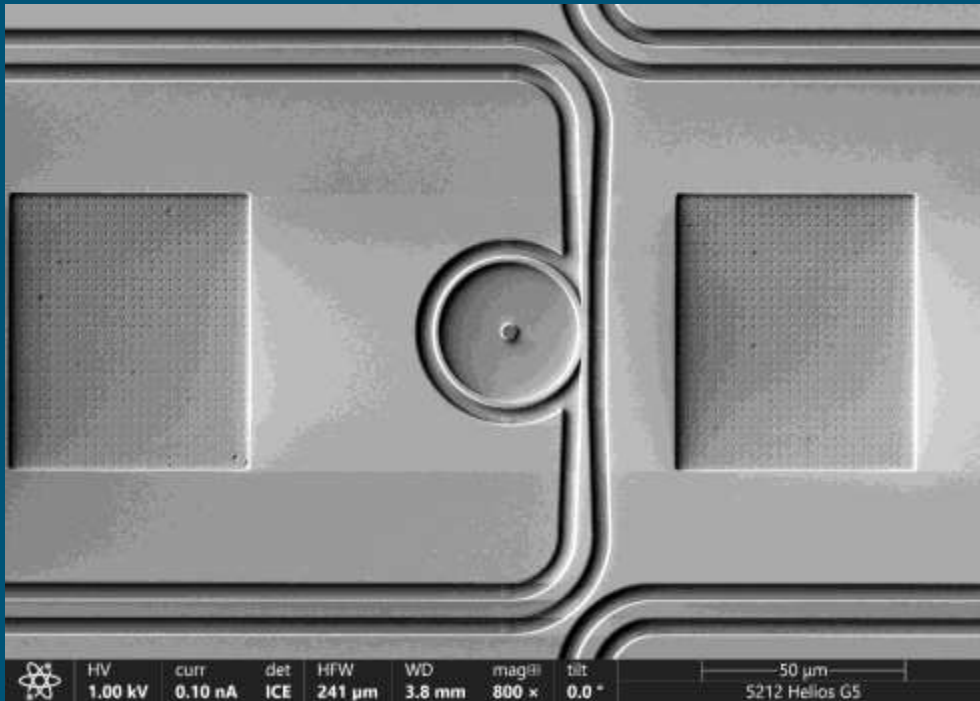
Can achieve trapping strengths (frequencies) of 50 MHz to 100 MHz, compared to current traps with 5 MHz to 10 MHz trapping strengths.

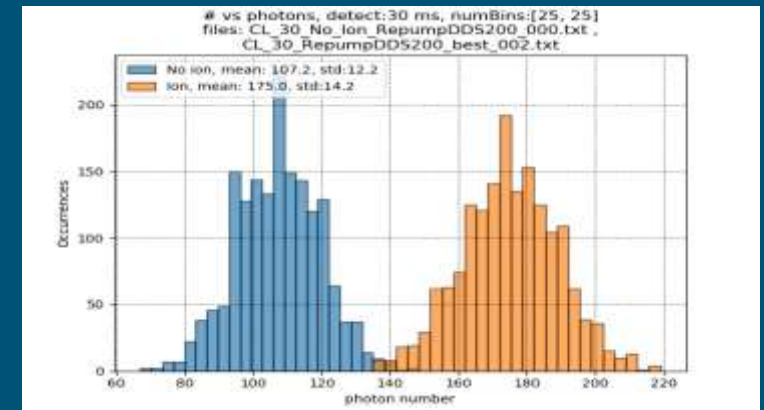
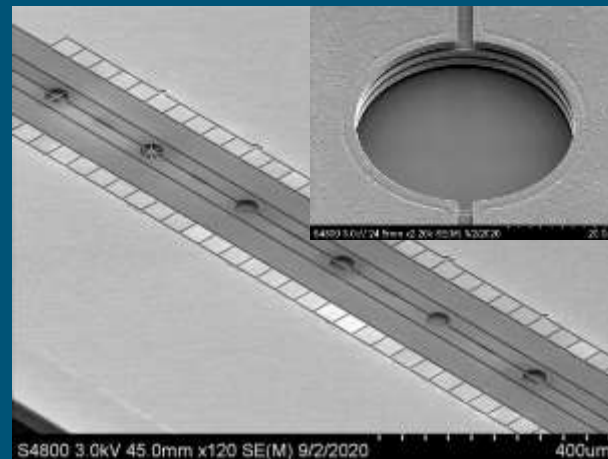
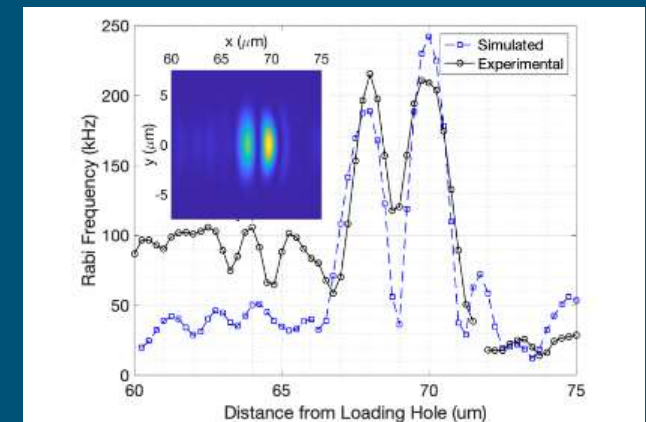
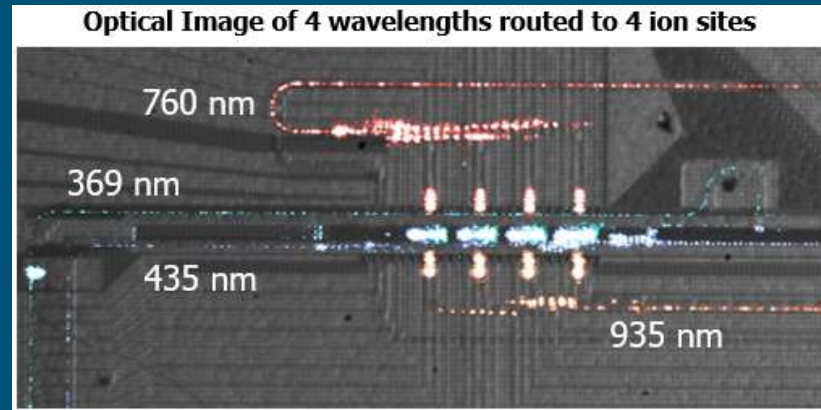
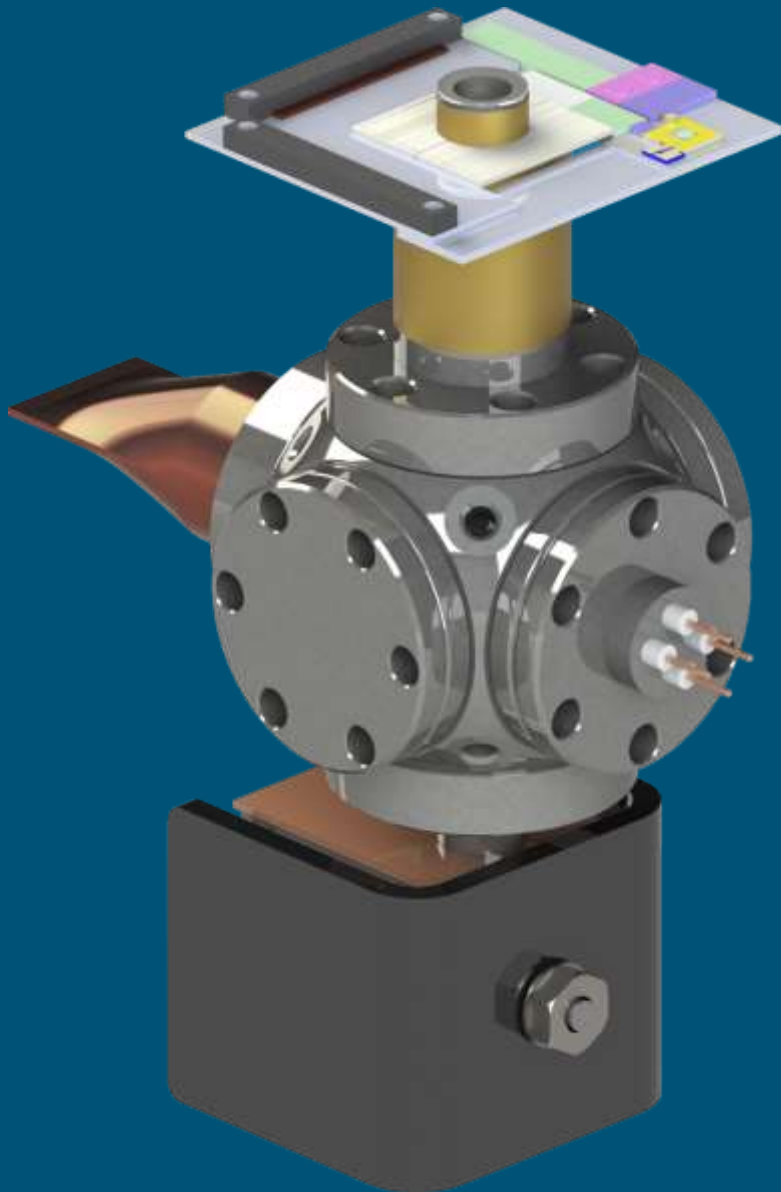


Optical modulators: piezo-activated aluminum nitride rings



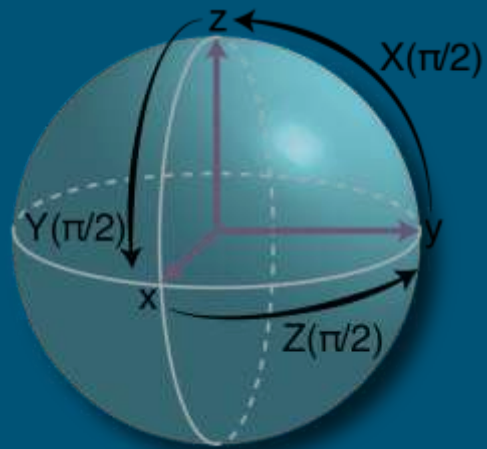
On-chip optical modulators can make the devices more compact, robust, and reproducible. However the wavelength, size limitations, and process compatibility make this a challenging problem.





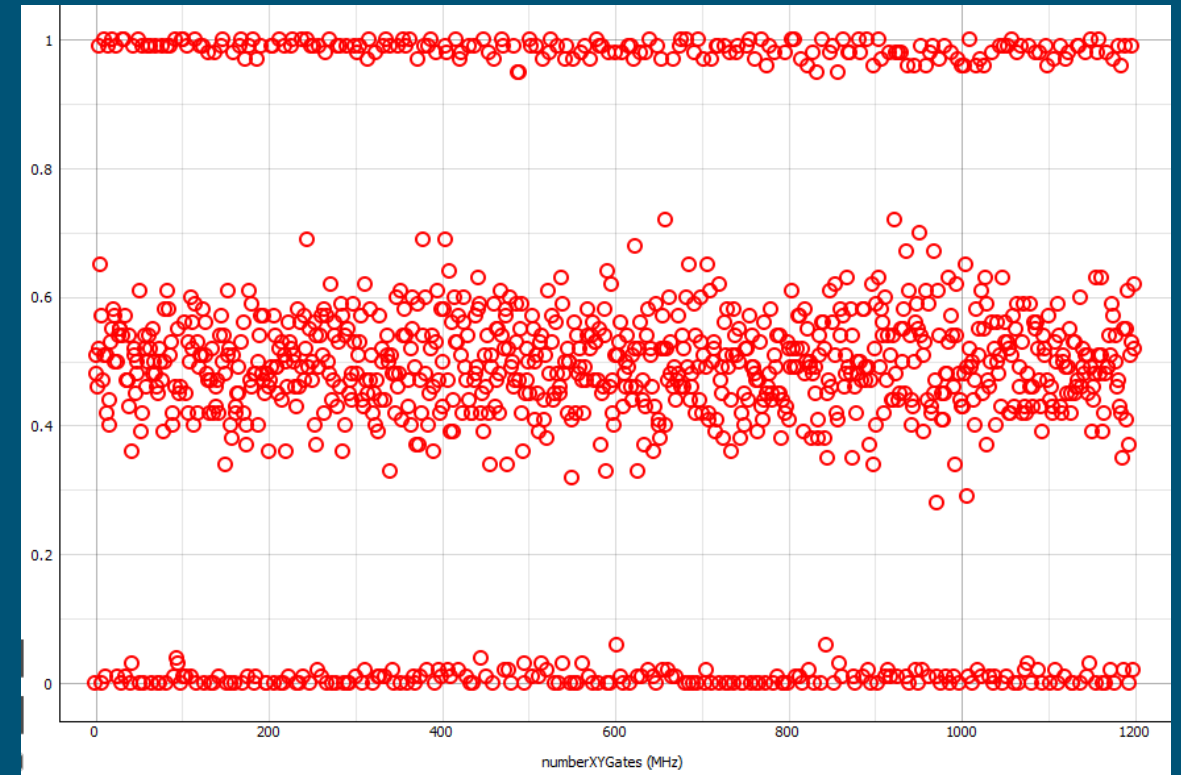
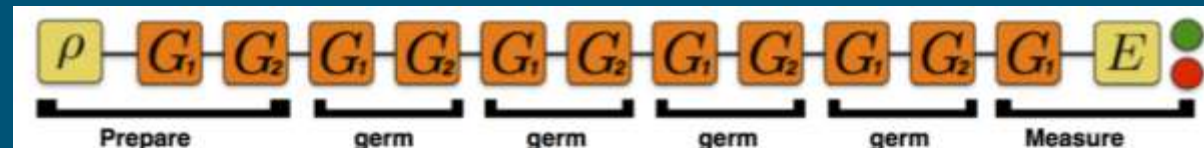
Gate Set Tomography (GST)

- No calibration required
- Detailed debug information
- Efficiently measures performance characterizing fault-tolerance (diamond norm)
- Amplifies errors
- Detects non-Markovian noise
- Robin Blume-Kohout, Kevin Young, Eric Nielsen, SNL



Desired “target” gates:

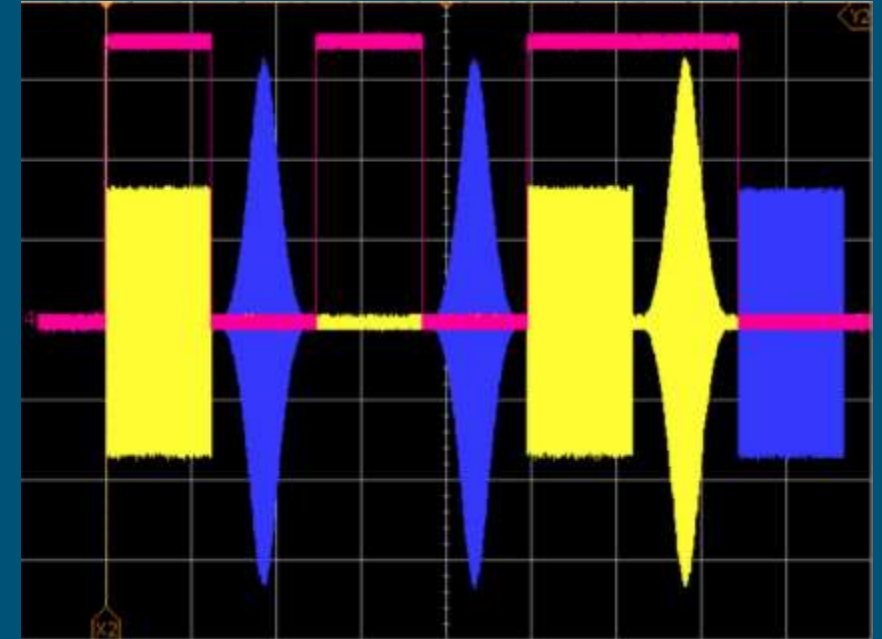
G_i Idle (Identity)
 G_x $\pi/2$ rotation about x -axis
 G_y $\pi/2$ rotation about y -axis



Ion trapping at Sandia



- QSCOUT: Quantum Scientific Open User Testbed
 - https://www.sandia.gov/quantum/Projects/QSCOUT_Call2021.html
 - **Proposals due June 18!**
- Quantum Systems Accelerator (NQI center)
 - Many collaborators, electronics and fabrication
- QSENSE (NQI collaboration with Jim Plusquellic, Eirini Tsiropoulou, Nafis Irtija)
 - FPGA control system
- DARPA TICTOC (ion clock)
- DOE
 - Light modulation
 - Light delivery
 - Single mode light collection
- IARPA LogiQ
 - Trap characterization, collaboration
- LPS
 - High frequency, very small ion traps



We are frequently looking for postdocs (including now)!

Acknowledgments



Experiments

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Melissa Revelle
Will Setzer
Jon Sterk
Dan Stick
Josh Wilson
Christopher Yale

Trap design, fab, packaging

Matthew Blain
Jason Dominguez
Ray Haltli
Ed Heller
Tipp Jennings
Becky Loviza
John Rembetski
Corrie Sadler
Ben Thurston
Jay Van Der Wall

Integrated optics

Daniel Dominguez
Matt Eichenfield
Mike Gehl
Galen Hoffman
Rex Kay
Andrew Leenheer

